

DATA SHEET

NEC

MOS INTEGRATED CIRCUIT μ PD3720A

2700 PIXELS $\times$ 3 COLOR CCD LINEAR IMAGE SENSOR

The μ PD3720A is a color CCD (Charge Coupled Device) linear image sensor which changes optical images to electrical signal and has the function of color separation.

The μ PD3720A has 3 rows of 2700 pixels and 3 pairs of 2 rows of 1350-bit charge transferred registers, reset feed-through level clamp circuits, clamp pulse generation circuit and voltage amplifiers. It is suitable for color image scanners, color facsimiles and so on.

FEATURES

- Valid photocell : 2700 pixels $\times$ 3
- Photocell's pitch : 10.5 μ m
- Line spacing : 42 μ m (4 lines) Red line-Green line, Green line-Blue line
- Color filter : Primary colors (red, green and blue), pigment filter (with light resistance 10^7 lx $\cdot$ hour)
- Resolution : 12 dot/mm A4 (210 $\times$ 297 mm) size (shorter side)
300 dpi US letter (8.5" $\times$ 11") size (shorter side)
- Drive clock level : CMOS output under 5 V operation
- Data rate : 3 MHz MAX.
- Power supply : +12 V
- On-chip circuits : Reset feed-through level clamp circuits
Clamp pulse generation circuit
Voltage amplifiers
- Pin assign : Compatible with the μ PD3720

ORDERING INFORMATION

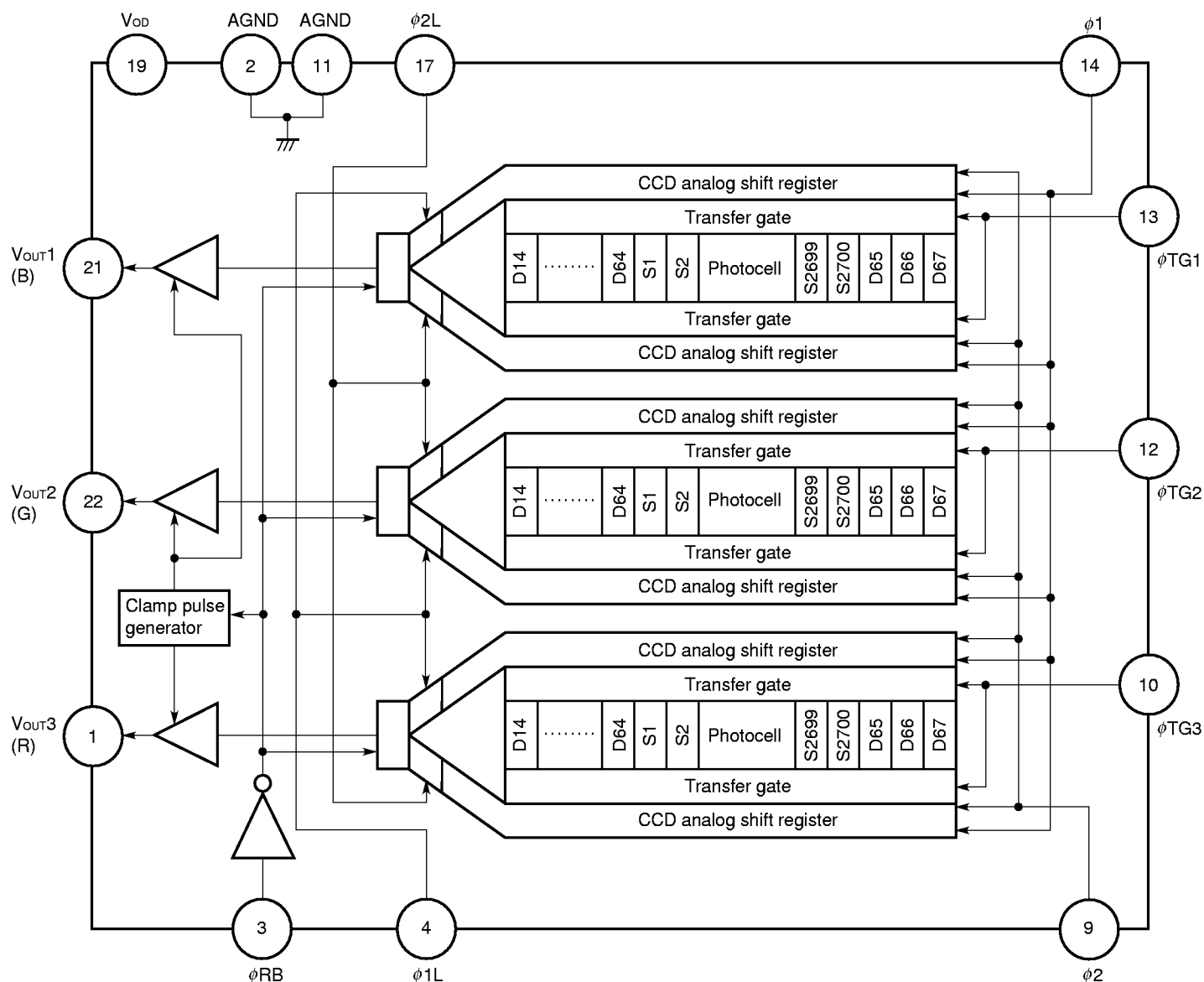
Part Number	Package
μ PD3720ACY	CCD linear image sensor 22-pin plastic DIP (400 mil)

The information in this document is subject to change without notice.

COMPARISON CHART

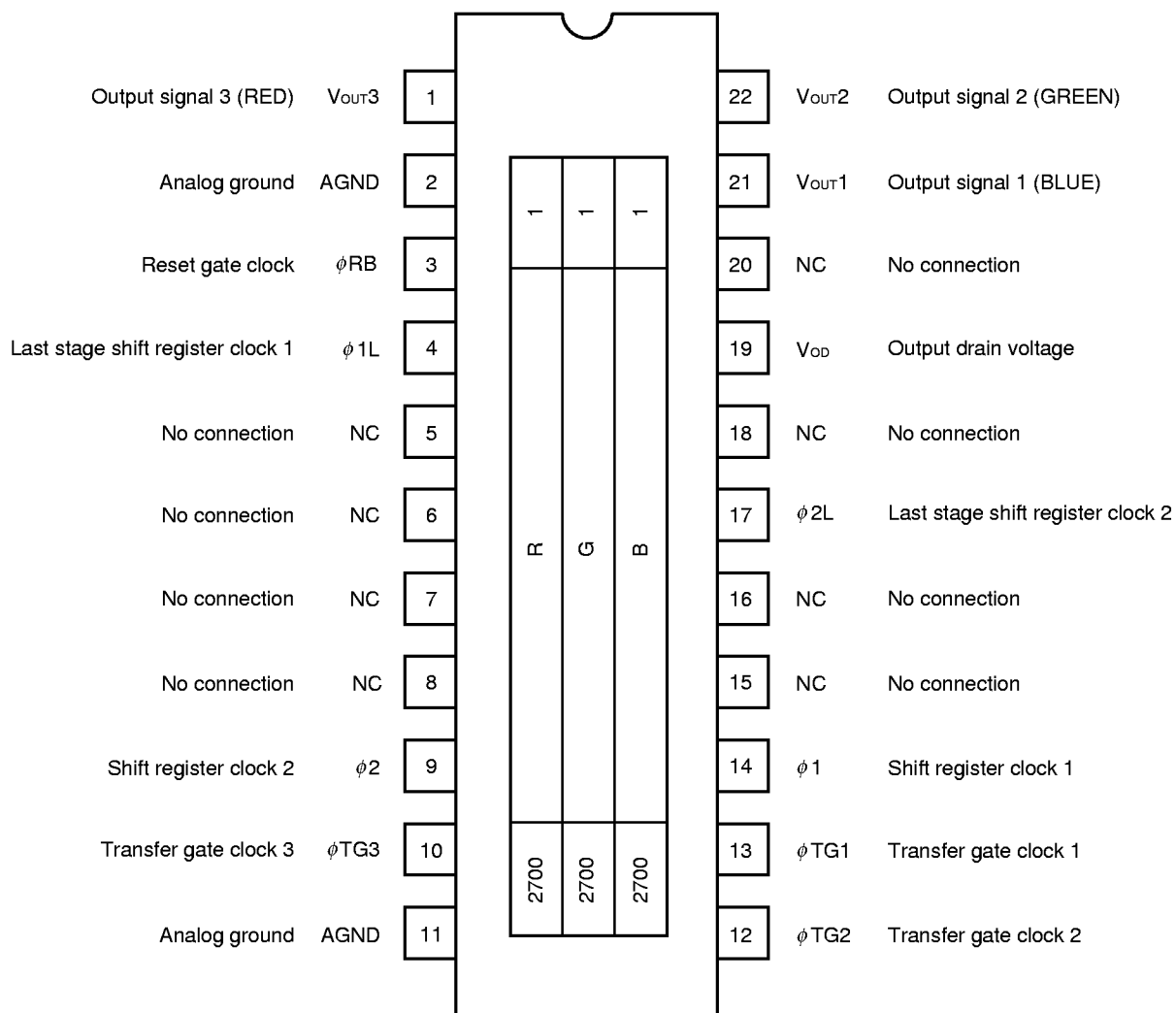
Item		μ PD3720A	μ PD3720
PIN CONFIGURATION	Pin 11	Analog ground	Digital ground
ELECTRICAL CHARACTERISTICS	Output fall delay time TYP. (ns)	70	80
TIMING CHART	Output signal waveform	Spike noise reduced	—

BLOCK DIAGRAM

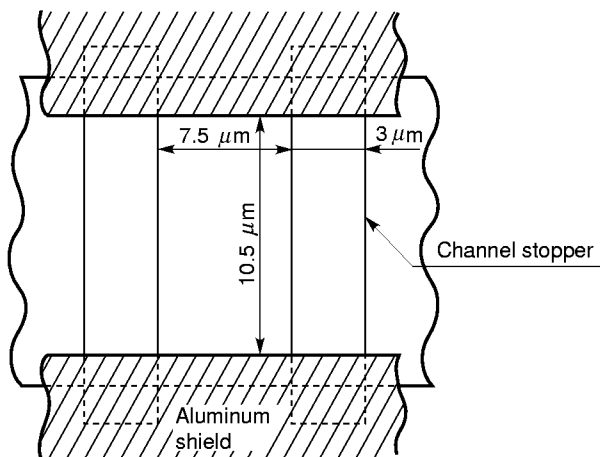


PIN CONFIGURATION (Top View)

CCD linear image sensor 22-pin plastic DIP(400 mil)



PHOTOCELL STRUCTURE DIAGRAM



ABSOLUTE MAXIMUM RATINGS ($T_A = +25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Ratings	Unit
Output drain voltage	V_{OD}	-0.3 to +15	V
Shift register clock voltage	$V_{\phi1}, V_{\phi2}, V_{\phi1L}, V_{\phi2L}$	-0.3 to +15	V
Reset gate clock voltage	$V_{\phi RB}$	-0.3 to +15	V
Transfer gate clock voltage	$V_{\phi TG1} - V_{\phi TG3}$	-0.3 to +15	V
Operating ambient temperature	T_A	-25 to +60	$^{\circ}\text{C}$
Storage temperature	T_{stg}	-40 to +70	$^{\circ}\text{C}$

Caution Exposure to **ABSOLUTE MAXIMUM RATINGS** for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The parameters apply independently.

RECOMMENDED OPERATING CONDITIONS ($T_A = +25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Output drain voltage	V_{OD}	11.4	12.0	12.6	V
Shift register clock signal high level	$V_{\phi1H}, V_{\phi2H}, V_{\phi1LH}, V_{\phi2LH}$	4.5	5.0	5.5	V
Shift register clock signal low level	$V_{\phi1L}, V_{\phi2L}, V_{\phi1LL}, V_{\phi2LL}$	-0.3	0	+0.5	V
Reset gate clock high level	$V_{\phi RBH}$	4.5	5.0	5.5	V
Reset gate clock low level	$V_{\phi RBL}$	-0.3	0	+0.5	V
Transfer gate clock high level	$V_{\phi TG1H} - V_{\phi TG3H}$	4.5	5.0	5.5	V
Transfer gate clock low level	$V_{\phi TG1L} - V_{\phi TG3L}$	-0.3	0	+0.5	V
Data rate	$f_{\phi RB}$	—	1	3	MHz

ELECTRICAL CHARACTERISTICS

($T_A = +25\text{ }^{\circ}\text{C}$, $V_{OD} = 12\text{ V}$, $f_{\phi RB} = 1\text{ MHz}$, data rate = 1 MHz, storage time = 5 ms,
light source: 3200 K halogen lamp +C-500S (infrared cut filter, $t = 1\text{ mm}$), input signal clock = 5 V_{p-p})

Parameter		Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Saturation voltage		V_{sat}		2.0	3.0	—	V
Saturation exposure	Red	SER			0.15		$\text{lx}\cdot\text{s}$
	Green	SEG			0.16		$\text{lx}\cdot\text{s}$
	Blue	SEB			0.27		$\text{lx}\cdot\text{s}$
Photo response non-uniformity		PRNU	$V_{OUT} = 1\text{ V}$		6	20	%
Average dark signal		ADS	Light shielding		0.5	2.5	mV
Dark signal non-uniformity		DSNU	Light shielding		1.5	8.0	mV
Power consumption		P_W			400	600	mW
Output impedance		Z_o			0.5	1	$k\Omega$
Response	Red	R_R		14.14	20.20	26.26	$\text{V}/\text{lx}\cdot\text{s}$
	Green	R_G		12.95	18.50	24.05	$\text{V}/\text{lx}\cdot\text{s}$
	Blue	R_B		7.77	11.10	14.43	$\text{V}/\text{lx}\cdot\text{s}$
Image lag		IL	$V_{OUT} = 1\text{ V}$		2	10	%
Offset level Note1		V_{OS}		3	4.5	6.6	V
Output fall delay time Note2		t_d	$V_{OUT} = 1\text{ V}$		70		ns
Total transfer efficiency		TTE	$V_{OUT} = 1\text{ V}$, data rate = 3 MHz	92	98		%
Register imbalance		RI	$V_{OUT} = 1\text{ V}$	0	1.0	4.0	%
Response peak	Red				630		nm
	Green				540		nm
	Blue				460		nm
Dynamic range		DR1	V_{sat} / DSNU		2000		times
		DR2	V_{sat} / σ		3000		times
Reset feed-through noise Note1		RFTN	Light shielding	−1000	−300	+300	mV
Random noise		σ	Light shielding	—	1.0	—	mV

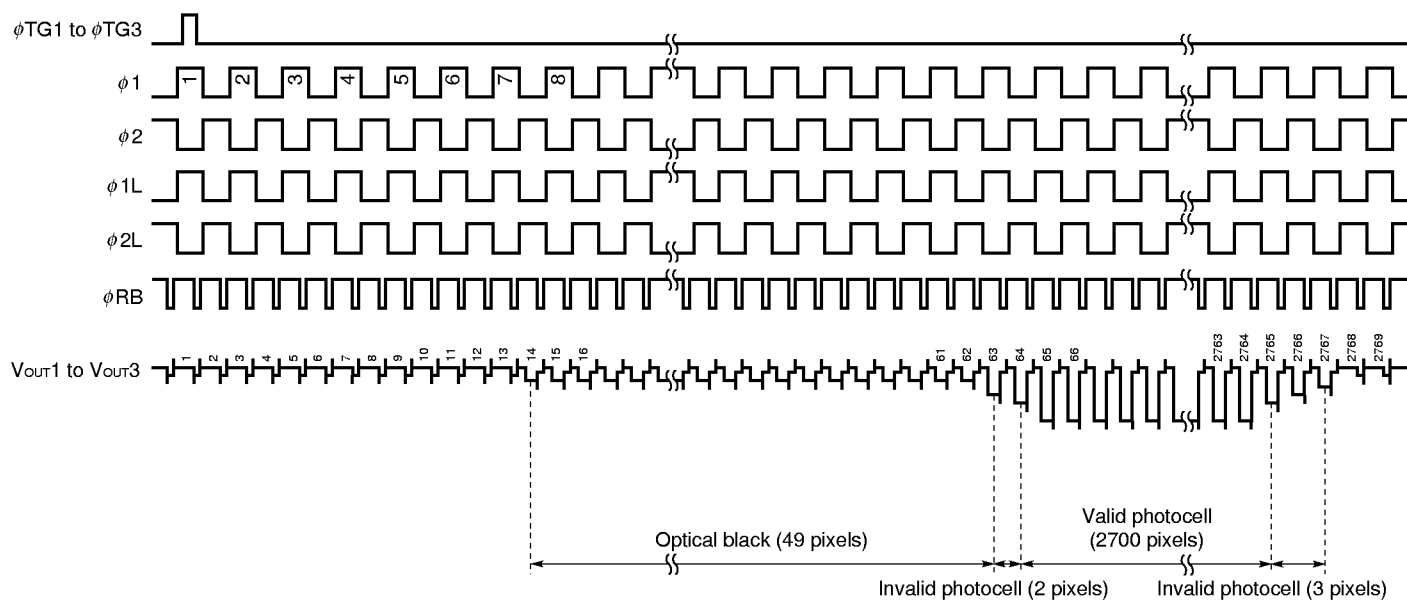
Notes 1. Refer to **TIMING CHART2**.

2. When each fall delay time of $\phi 1L$ and $\phi 2L$ (t_2' , t_1') is the TYP. value (refer to **TIMING CHART 2**).

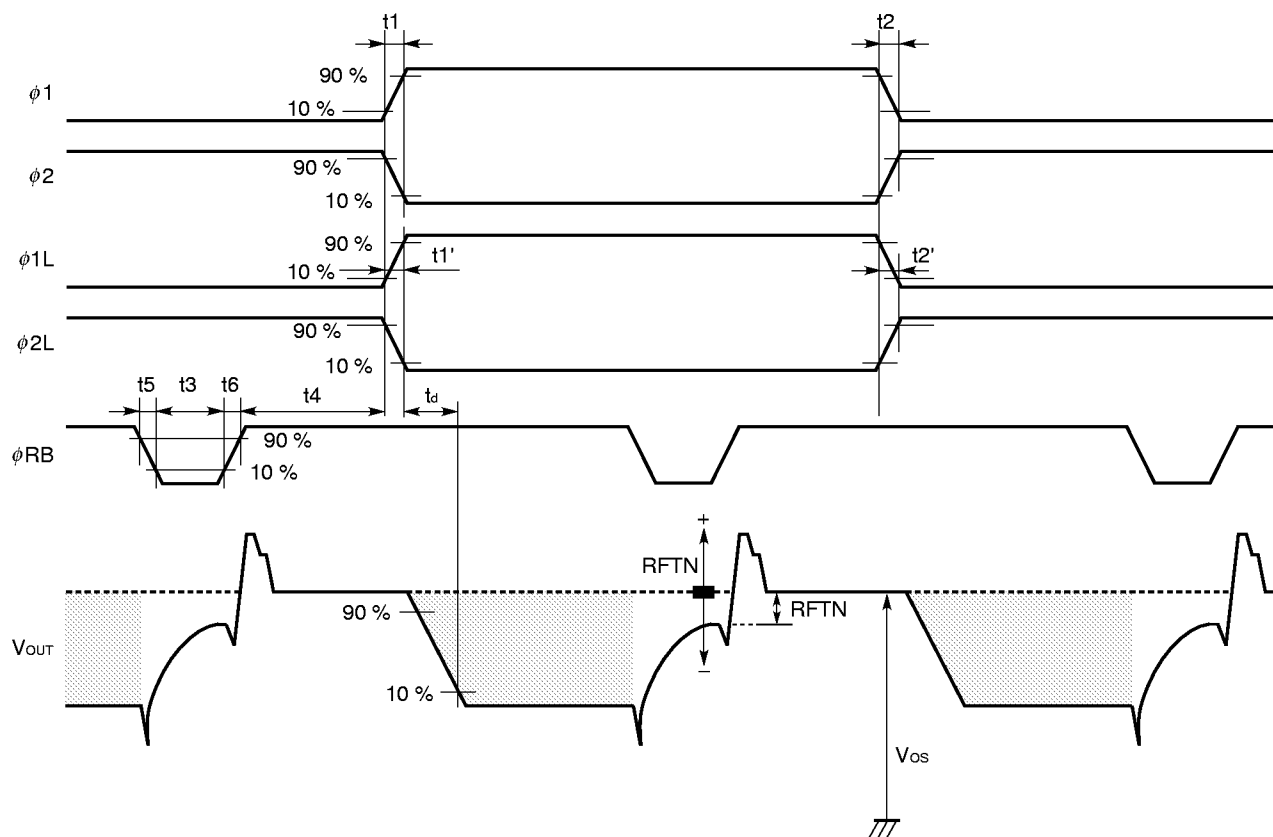
INPUT PIN CAPACITANCE

Parameter	Symbol	Pin name	Pin No.	MIN.	TYP.	MAX.	Unit
Transfer gate clock pin capacitance	$C_{\phi TG}$	$\phi TG1$	13		200		pF
		$\phi TG2$	12		200		pF
		$\phi TG3$	10		200		pF
Reset gate clock pin capacitance	$C_{\phi RB}$	ϕRB	3		50		pF
Last stage shift register clock pin capacitance	$C_{\phi L}$	$\phi 1L$	4		30		pF
		$\phi 2L$	17		30		pF
Shift register clock pin capacitance 1	$C_{\phi 1}$	$\phi 1$	14		700		pF
Shift register clock pin capacitance 2	$C_{\phi 2}$	$\phi 2$	9		700		pF

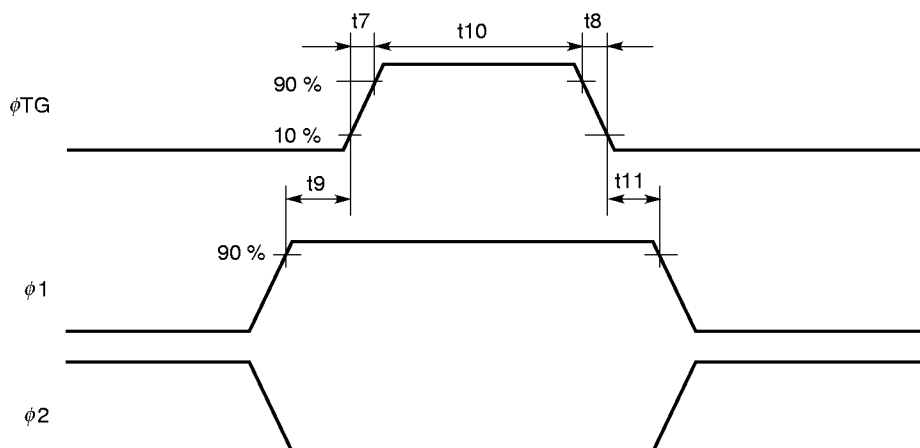
TIMING CHART 1 (for each color)



TIMING CHART 2 (for each color)

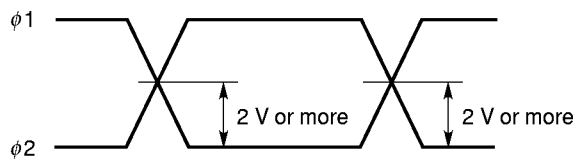


ϕ TG1 to ϕ TG3, ϕ 1, ϕ 2 TIMING CHART

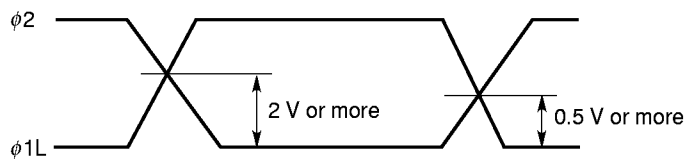


Symbol	MIN.	TYP.	MAX.	Unit
t_1, t_2	0	50	—	ns
t_1', t_2'	0	5	—	ns
t_4	130	300	—	ns
t_3	20	150	—	ns
t_5, t_6	0	50	—	ns
t_7, t_8	0	50	—	ns
t_9, t_{11}	900	1000	—	ns
t_{10}	3000	10000	—	ns

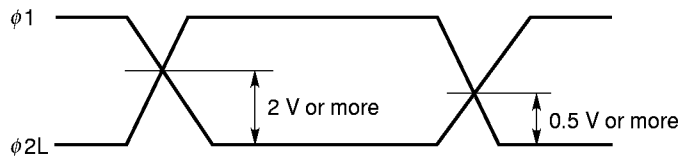
ϕ 1, ϕ 2 cross points



ϕ 1L, ϕ 2 cross points



ϕ 1, ϕ 2L cross points



Remark Adjust cross points (ϕ 1, ϕ 2), (ϕ 1L, ϕ 2) and (ϕ 1, ϕ 2L) with input resistance of each pin.

DEFINITIONS OF CHARACTERISTIC ITEMS

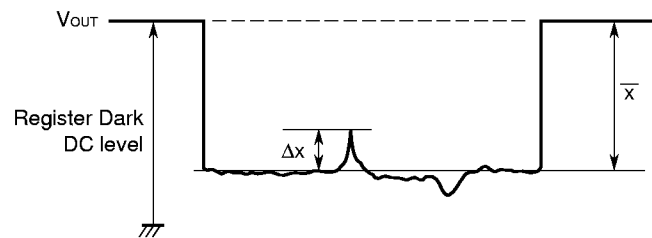
1. Saturation voltage: V_{sat}
Output signal voltage at which the response linearity is lost.
2. Saturation exposure: SE
Product of intensity of illumination (lx) and storage time(s) when saturation of output voltage occurs.
3. Photo response non-uniformity: PRNU
The output signal non-uniformity of all the valid pixels when the photosensitive surface is applied with the light of uniform illumination. This is calculated by the following formula.

$$\text{PRNU (\%)} = \frac{\Delta x}{\bar{x}} \times 100$$

Δx : maximum of $|x_j - \bar{x}|$

$$\bar{x} = \frac{\sum_{j=1}^{2700} x_j}{2700}$$

x_j : Output voltage of valid pixel number j



4. Average dark signal: ADS
Average output signal voltage of all the valid pixels at light shielding. This is calculated by the following formula.

$$\text{ADS (mV)} = \frac{\sum_{j=1}^{2700} d_j}{2700}$$

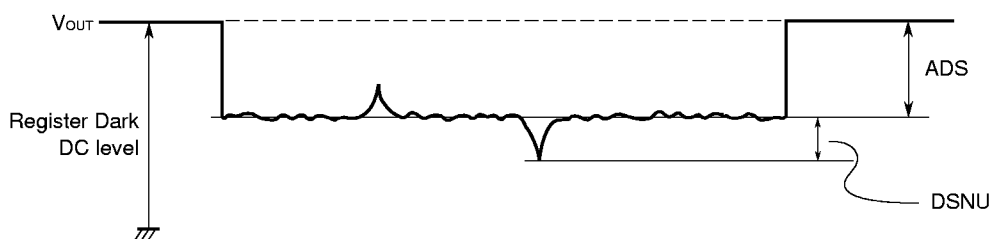
d_j : Dark signal of valid pixel number j

5. Dark signal non-uniformity: DSNU

Absolute maximum of the difference between ADS and voltage of the highest or lowest output pixel of all the valid pixels at light shielding. This is calculated by the following formula.

$$\text{DSNU (mV): maximum of } |d_j - \text{ADS}| \text{ } j = 1 \text{ to } 2700$$

d_j : Dark signal of valid pixel number j



6. Output impedance: Z_o

Impedance of the output pins viewed from outside.

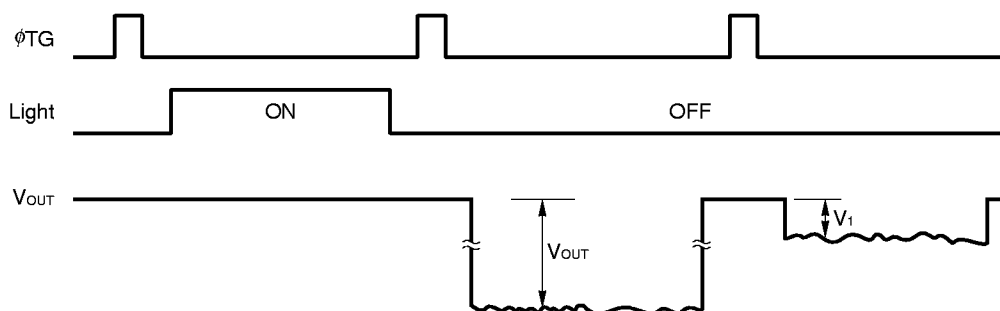
7. Response: R

Output voltage divided by exposure ($I \times s$).

Note that the response varies with a light source (spectral characteristic).

8. Image Lag: IL

The rate between the last output voltage and the next one after read out the data of a line.



$$\text{IL (\%)} = \frac{V_1}{V_{\text{OUT}}} \times 100$$

9. Register Imbalance: RI

The rate of the difference between the averages of the output voltage of Odd and Even pixels, against the average output voltage of all the valid pixels.

$$RI (\%) = \frac{\frac{2}{n} \left| \sum_{j=1}^{\frac{n}{2}} (V_{2j-1} - V_{2j}) \right|}{\frac{1}{n} \sum_{j=1}^n V_j} \times 100$$

n : Number of valid pixels

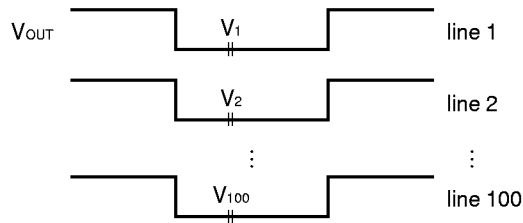
V_j : Output voltage of each pixel

10. Random noise: σ

Random noise σ is defined as the standard deviation of a valid pixel output signal with 100 times (=100 lines) data sampling at dark (light shielding).

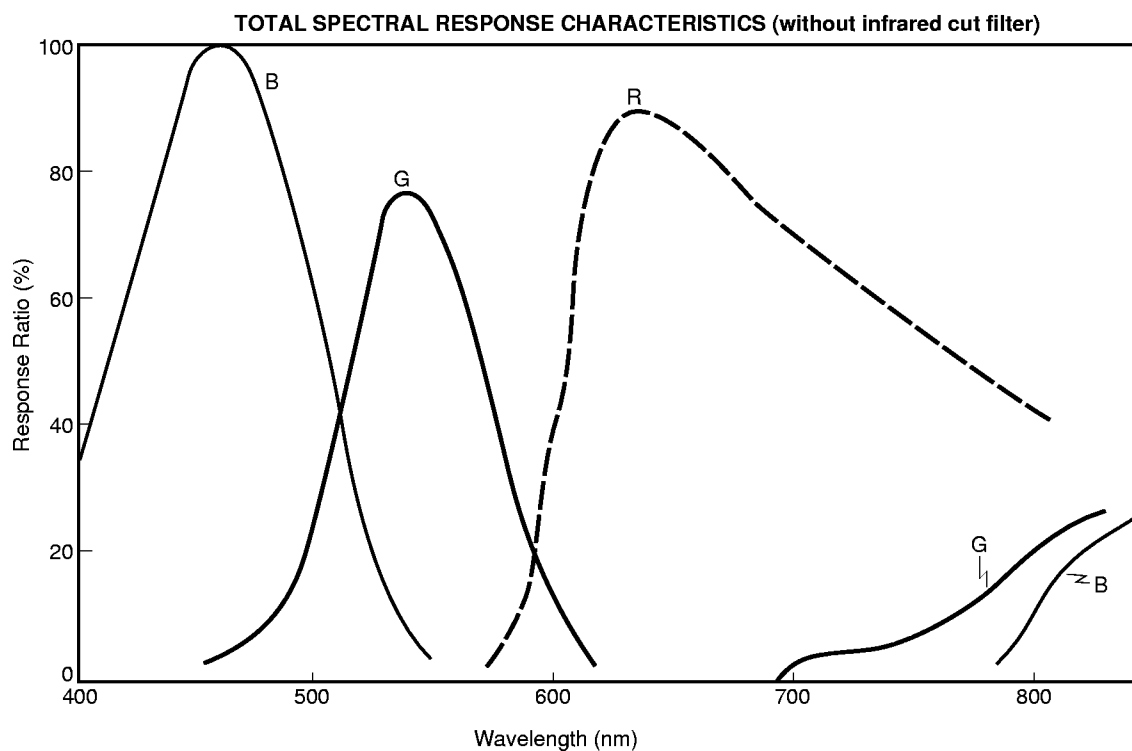
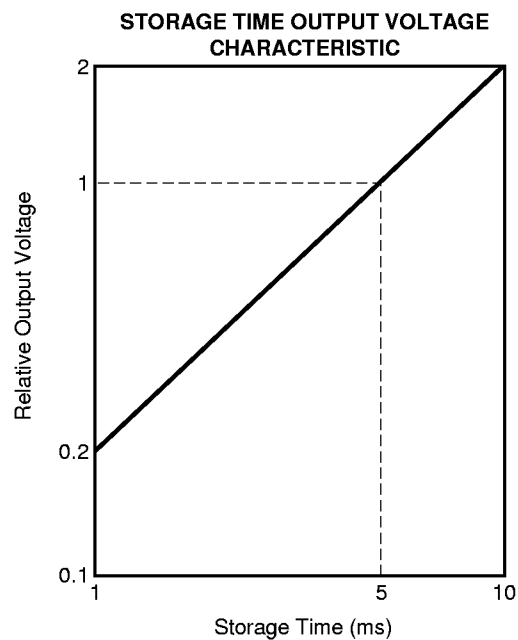
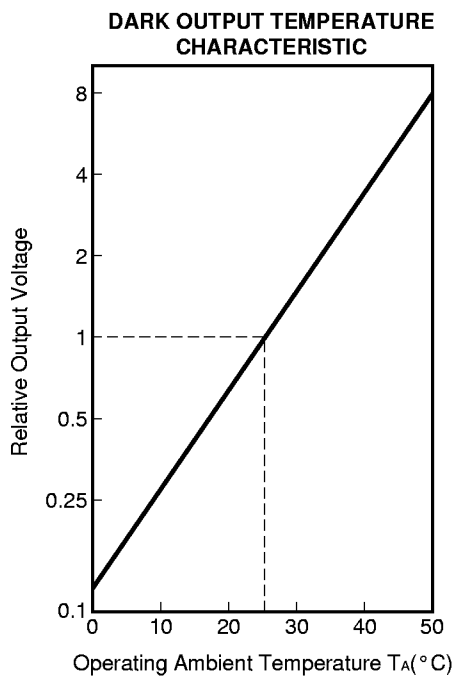
$$\sigma = \sqrt{\frac{\sum_{i=1}^{100} (V_i - \bar{V})^2}{100}}, \quad \bar{V} = \frac{1}{100} \sum_{i=1}^{100} V_i$$

V_i : A valid pixel output signal among all of the valid pixels for each color

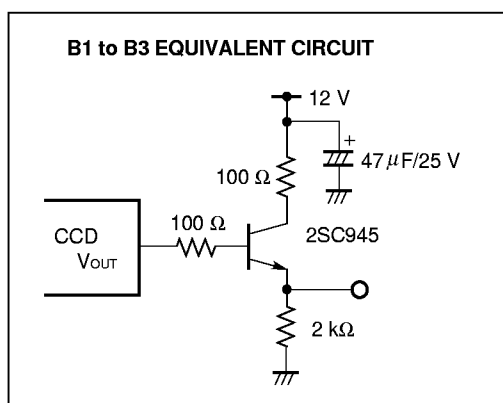
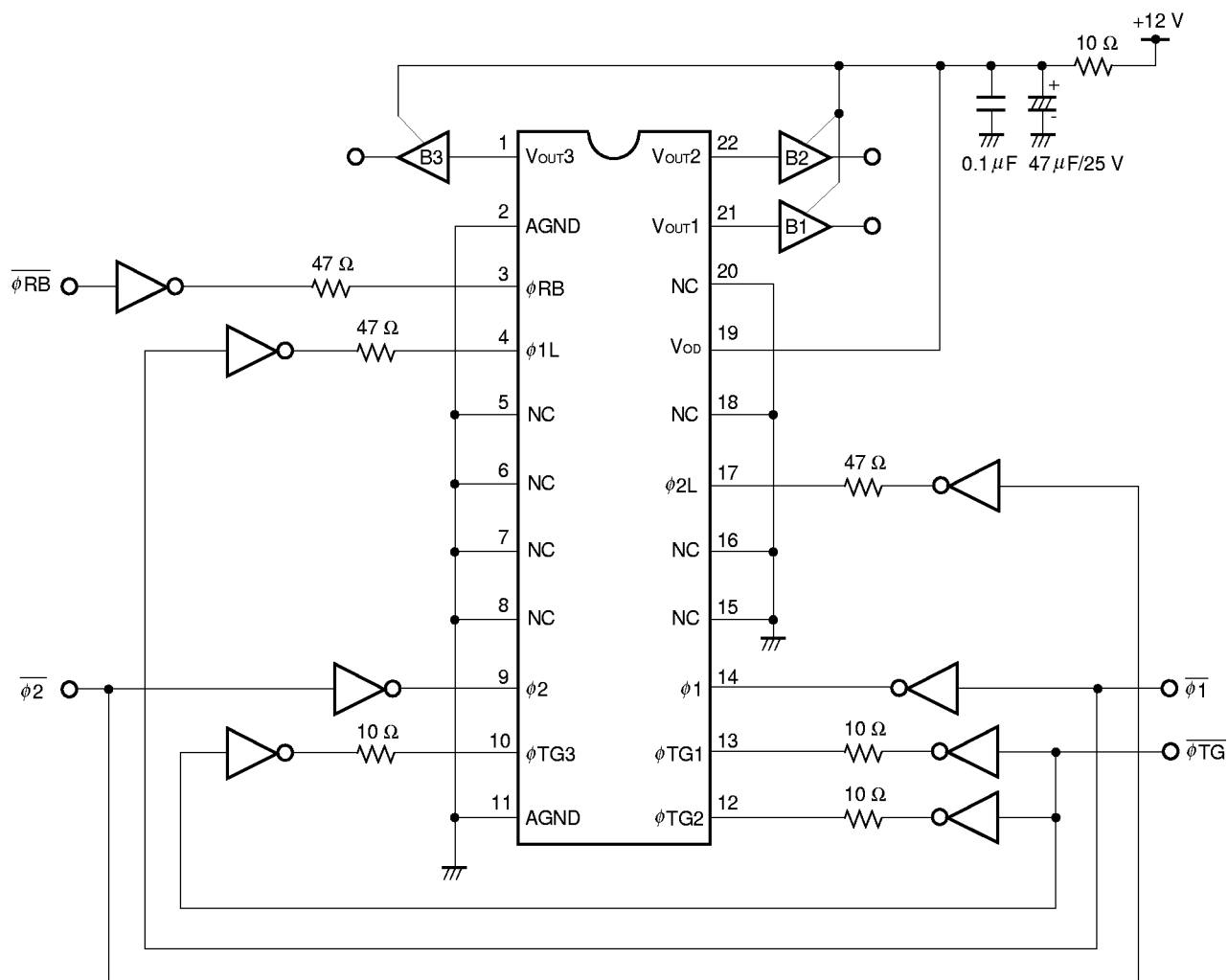


This is measured by the DC level sampling of only the signal level, not by CDS (Correlated Double Sampling).

STANDARD CHARACTERISTIC CURVES ($T_A = +25\text{ }^{\circ}\text{C}$)



APPLICATION CIRCUIT EXAMPLE

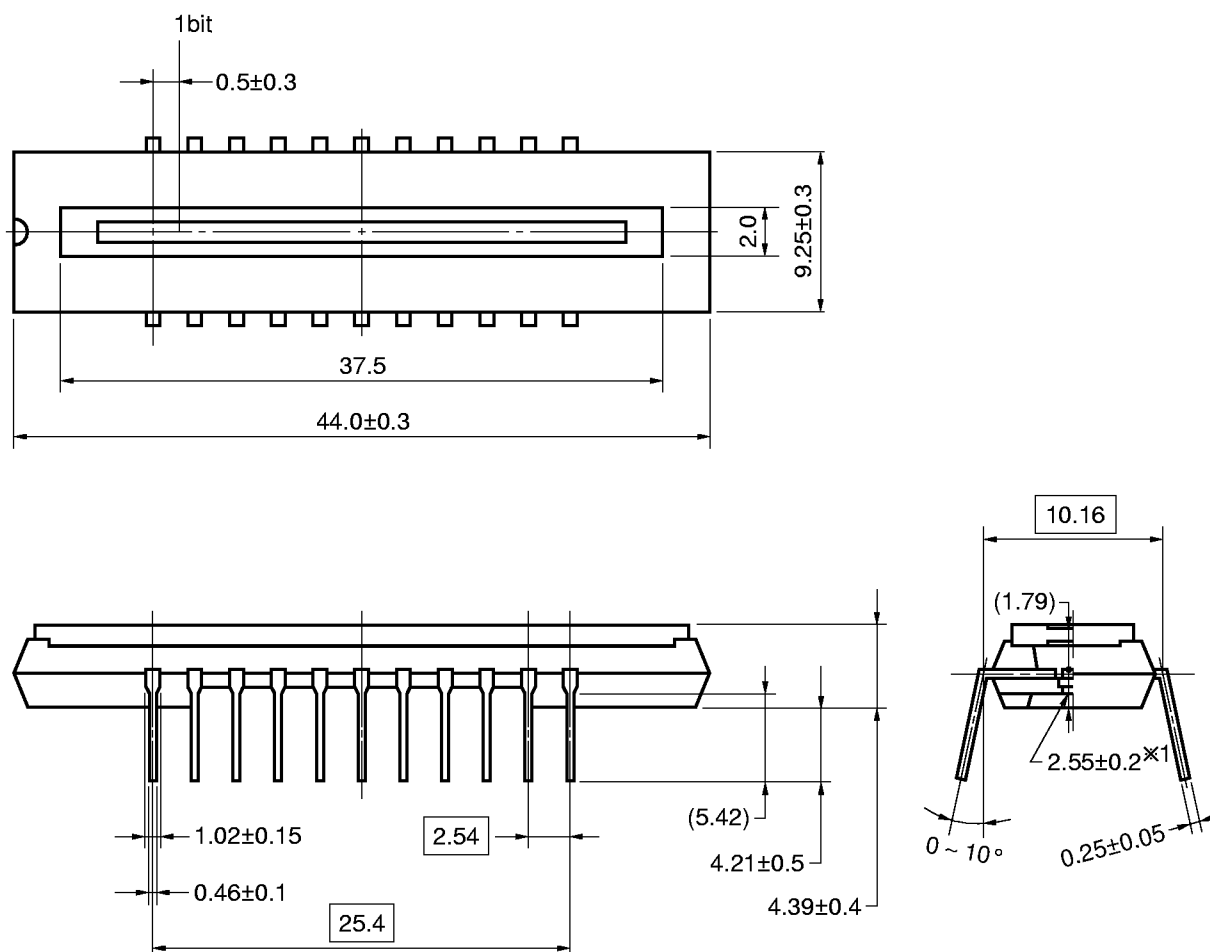


Remark Inverters : μ PD74HC04

PACKAGE DRAWING

CCD LINEAR IMAGE SENSOR 22PIN PLASTIC DIP (400 mil)

(Unit : mm)



Name	Dimensions	Refractive index
Plastic cap	$42.9 \times 8.35 \times 0.7 \times 2$	1.5

※1 The bottom of the package ↔ The surface of the chip

※2 The thickness of the cap over the chip

22C-1CCD-PKG6

RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below.

If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "**Semiconductor Device Mounting Technology Manual**"(C10535E).

Type of Through-hole Device

μ PD3720ACY: CCD linear image sensor 22-pin plastic DIP (400 mil)

Process	Conditions
Wave soldering (only to leads)	Solder temperature: 260 °C or below, Flow time: 10 seconds or less.
Partial heating method	Pin temperature: 260 °C or below, Heat time: 10 seconds or less (per each lead).

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body dose not get jet soldered.

During assembly care should be taken to prevent solder or flux from contacting the plastic cap.

The optical characteristics could be degraded by such contact.

NOTES ON CLEANING THE PLASTIC CAP

① CLEANING THE PLASTIC CAP

Care should be taken when cleaning the surface to prevent scratches.

The optical characteristics of the CCD will be degraded if the cap is scratched during cleaning.

We recommend cleaning the cap with a soft cloth moistened with one of the recommended solvents below. Excessive pressure should not be applied to the cap during cleaning. If the cap requires multiple cleanings it is recommended that a clean surface or cloth be used.

② RECOMMENDED SOLVENTS

The following are the recommended solvents for cleaning the CCD plastic cap. Use of solvents other than these could result in optical or physical degradation in the plastic cap. Please consult your sales office when considering an alternative solvent.

Solvents	Symbol
Ethyl Alcohol	EtOH
Methyl Alcohol	MeOH
Isopropyl Alcohol	IPA
N-methyl Pyrrolidone	NMP